BLF7G20L-200; BLF7G20LS-200 Power LDMOS transistor Rev. 5 — 1 September 2015

AMMPLEON

Product data sheet

Product profile

1.1 General description

200 W LDMOS power transistor for base station applications at frequencies from 1805 MHz to 1990 MHz.

Typical performance Table 1.

Typical RF performance at $T_{case} = 25$ °C in a common source class-AB production test circuit.

Mode of operation	f	I_{Dq}	V _{DS}	$P_{L(AV)}$	Gp	η_D	ACPR
	(MHz)	(mA)	(V)	(W)	(dB)	(%)	(dBc)
2-carrier W-CDMA	1805 to 1880	1620	28	55	18	33	-29 <u>[1]</u>

^[1] Test signal: 3GPP; test model 1; 64 PDPCH; PAR = 8.4 dB at 0.01 % probability on CCDF.

1.2 Features and benefits

- Excellent ruggedness
- High efficiency
- Low R_{th} providing excellent thermal stability
- Designed for broadband operation (1805 MHz to 1990 MHz)
- Lower output capacitance for improved performance in Doherty applications
- Designed for low-memory effects providing excellent digital pre-distortion capability
- Internally matched for ease of use
- Integrated ESD protection
- Compliant to Restriction of Hazardous Substances (RoHS) Directive 2002/95/EC

1.3 Applications

 RF power amplifiers for W-CDMA base stations and multi-carrier applications in the 1805 MHz to 1990 MHz frequency range

2. Pinning information

Table 2. Pinning

Table 2.	Filling		
Pin	Description	Simplified outline	Graphic symbol
BLF7G20	0L-200 (SOT502A)		
1	drain		,
2	gate	5 3	1 <u> </u>
3	source		2 —
			3 sym112
BLF7G20	DLS-200 (SOT502B)		,
1	drain		
2	gate	1 3	1
3	source	[1]	2
			3
			sym112

^[1] Connected to flange

3. Ordering information

Table 3. Ordering information

Type number	Packag	ge	
	Name	Description	Version
BLF7G20L-200	-	flanged LDMOST ceramic package; 2 mounting holes; 2 leads	SOT502A
BLF7G20LS-200	-	earless flanged LDMOST ceramic package; 2 leads	SOT502B

4. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V_{DS}	drain-source voltage		-	65	V
V_{GS}	gate-source voltage		-0.5	+13	V
T _{stg}	storage temperature		-65	+150	°C
Tj	junction temperature		-	225	°C

5. Thermal characteristics

Table 5. Thermal characteristics

Symbol	Parameter	Conditions	Тур	Unit
$R_{\text{th(j-c)}}$	thermal resistance from junction to case	T_{case} = 80 °C; P_{L} = 55 W; V_{DS} = 28 V; I_{Dq} = 1620 mA	0.27	K/W

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6. Characteristics

Table 6. Characteristics

 $T_i = 25$ °C unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V _{(BR)DSS}	drain-source breakdown voltage	$V_{GS} = 0 \text{ V}; I_D = 1.5 \text{ mA}$	65	-	-	V
V _{GS(th)}	gate-source threshold voltage	V_{DS} = 10 V; I_{D} = 150 mA	1.5	1.9	2.3	V
I _{DSS}	drain leakage current	$V_{GS} = 0 \text{ V}; V_{DS} = 28 \text{ V}$	-	-	4.2	μΑ
I _{DSX}	drain cut-off current	$V_{GS} = V_{GS(th)} + 3.75 \text{ V};$ $V_{DS} = 10 \text{ V}$	42	50.6	-	Α
I _{GSS}	gate leakage current	V_{GS} = 11 V; V_{DS} = 0 V	-420	2.44	420	nA
9 _{fs}	forward transconductance	V_{DS} = 10 V; I_{D} = 7.5 A	-	18.6	-	S
R _{DS(on)}	drain-source on-state resistance	$V_{GS} = V_{GS(th)} + 3.75 \text{ V};$ $I_D = 5.25 \text{ A}$	-	0.093	-	Ω

7. Test information

Table 7. Functional test information

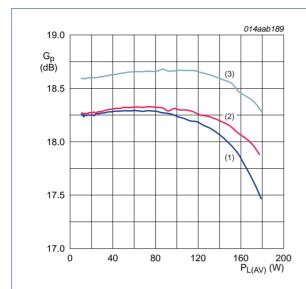
Mode of operation: 2-carrier W-CDMA; PAR = 8.4 dB at 0.01 % probability on the CCDF; 3GPP test model 1; 64 PDPCH; f_1 = 1807.5 MHz; f_2 = 1812.5 MHz; f_3 = 1872.5 MHz; f_4 = 1877.5 MHz; RF performance at V_{DS} = 28 V; I_{Dq} = 1620 mA; T_{case} = 25 °C; unless otherwise specified; in a class-AB production test circuit.

Parameter	Conditions	Min	Тур	Max	Unit
average output power		-	55	-	W
power gain	$P_{L(AV)} = 55 W$	17	18	-	dB
input return loss	$P_{L(AV)} = 55 W$	-	-	-10	dB
drain efficiency	$P_{L(AV)} = 55 W$	30	33	-	%
adjacent channel power ratio	$P_{L(AV)} = 55 W$	-	-29	-	dBc
	average output power power gain input return loss drain efficiency	average output power $ P_{L(AV)} = 55 \text{ W} $ input return loss $ P_{L(AV)} = 55 \text{ W} $ drain efficiency $ P_{L(AV)} = 55 \text{ W} $	average output power - power gain $P_{L(AV)} = 55 \text{ W}$ 17 input return loss $P_{L(AV)} = 55 \text{ W}$ - drain efficiency $P_{L(AV)} = 55 \text{ W}$ 30	average output power - 55 power gain $P_{L(AV)} = 55 \text{ W}$ 17 18 input return loss $P_{L(AV)} = 55 \text{ W}$ drain efficiency $P_{L(AV)} = 55 \text{ W}$ 30 33	average output power - 55 - power gain $P_{L(AV)} = 55 \text{ W}$ 17 18 - input return loss $P_{L(AV)} = 55 \text{ W}$ 10 drain efficiency $P_{L(AV)} = 55 \text{ W}$ 30 33 -

7.1 Ruggedness in class-AB operation

The BLF7G20L-200 and BLF7G20LS-200 are capable of withstanding a load mismatch corresponding to VSWR = 10 : 1 through all phases under the following conditions: V_{DS} = 30 V; I_{Dq} = 1620 mA; P_L = 185 W (CW); f = 1805 MHz to 1880 MHz.

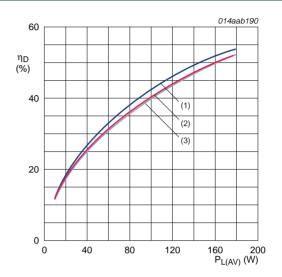
7.2 1 Tone CW



 V_{DS} = 28 V; I_{Dq} = 1620 mA.

- (1) f = 1805 MHz
- (2) f = 1845 MHz
- (3) f = 1880 MHz

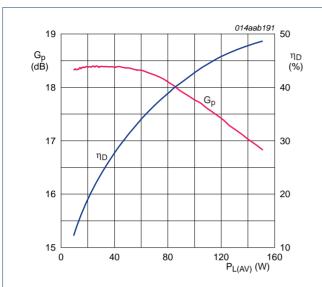
Fig 1. Power gain as a function of average output power; typical values



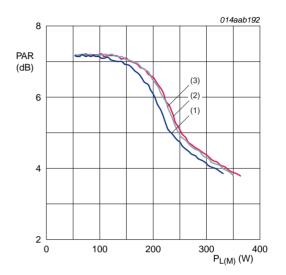
- V_{DS} = 28 V; I_{Dq} = 1620 mA.
- (1) f = 1805 MHz
- (2) f = 1845 MHz
- (3) f = 1880 MHz

Fig 2. Drain efficiency as a function of average output power; typical values

7.3 1-carrier W-CDMA



 V_{DS} = 28 V; I_{Dq} = 1620 mA; f = 1845 MHz; PAR = 7.2 dB at 0.01 % probability on the CCDF.

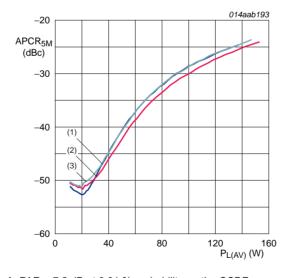


 V_{DS} = 28 V; I_{Dq} = 1620 mA; PAR = 7.2 dB at 0.01 % probability on the CCDF.

- (1) f = 1805 MHz
- (2) f = 1845 MHz
- (3) f = 1880 MHz

Fig 3. Power gain and drain efficiency as functions of average output power; typical values



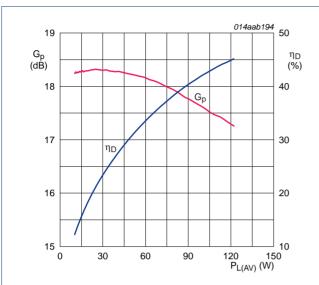


 V_{DS} = 28 V; I_{Dq} = 1620 mA; PAR = 7.2 dB at 0.01 % probability on the CCDF.

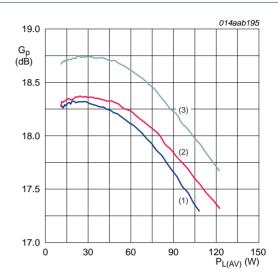
- (1) f = 1805 MHz
- (2) f = 1845 MHz
- (3) f = 1880 MHz

Fig 5. Adjacent power channel ratio (5 MHz) as function of average output power; typical values

7.4 2-carrier W-CDMA



 V_{DS} = 28 V; I_{Dq} = 1620 mA; channel spacing = 5 MHz; PAR = 8.4 dB at 0.01 % probability on the CCDF.



 V_{DS} = 28 V; I_{Dq} = 1620 mA; channel spacing = 5 MHz; PAR = 8.4 dB at 0.01 % probability on the CCDF.

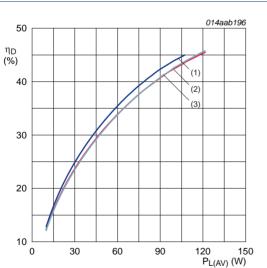
Power gain as a function of average output

- (1) f = 1805 MHz
- (2) f = 1845 MHz
- (3) f = 1880 MHz

power; typical values

Fig 7.

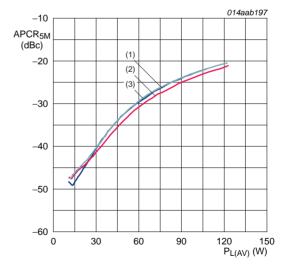
Fig 6. Power gain and drain efficiency as functions of average output power; typical values



 V_{DS} = 28 V; I_{Dq} = 1620 mA; channel spacing = 5 MHz; PAR = 8.4 dB at 0.01 % probability on the CCDF.

- (1) f = 1805 MHz
- (2) f = 1845 MHz
- (3) f = 1880 MHz

Fig 8. Drain efficiency as a function of average output power; typical values



 V_{DS} = 28 V; I_{Dq} = 1620 mA; channel spacing = 5 MHz; PAR = 8.4 dB at 0.01 % probability on the CCDF.

- (1) f = 1805 MHz
- (2) f = 1845 MHz
- (3) f = 1880 MHz

Fig 9. Adjacent power channel ratio (5 MHz) as a function of average output power; typical values

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7.5 Test circuit

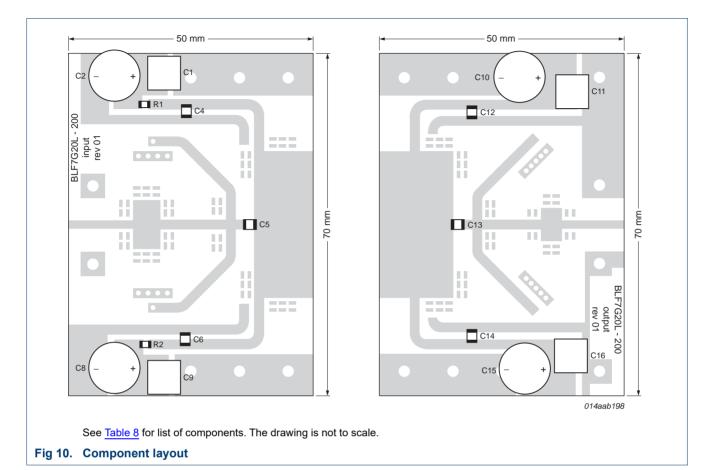


Table 8. List of components

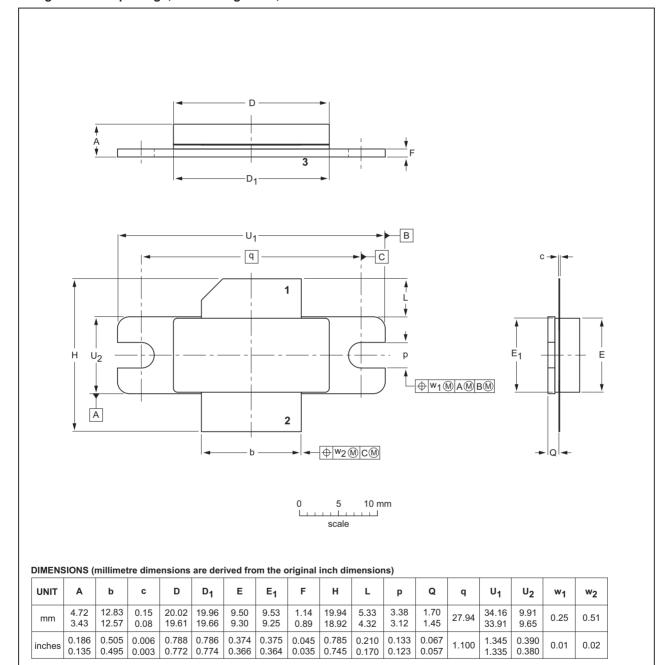
See <u>Figure 10</u> for component layout.

Component	Description	Value	Remarks
C1, C9, C11, C16	multilayer ceramic chip capacitor	10 μF	TDK
C4, C6	multilayer ceramic chip capacitor	68 pF	ATC800B
C5	multilayer ceramic chip capacitor	2.0 pF	ATC800B
C12, C14	multilayer ceramic chip capacitor	100 pF	ATC800B
C13	multilayer ceramic chip capacitor	3.3 pF	ATC800B
C2, C8, C10, C15	electrolytic capacitor	470 μF; 63 V	
R1, R2	chip resistor	10 Ω	Philips 0603

8. Package outline

Flanged ceramic package; 2 mounting holes; 2 leads

SOT502A

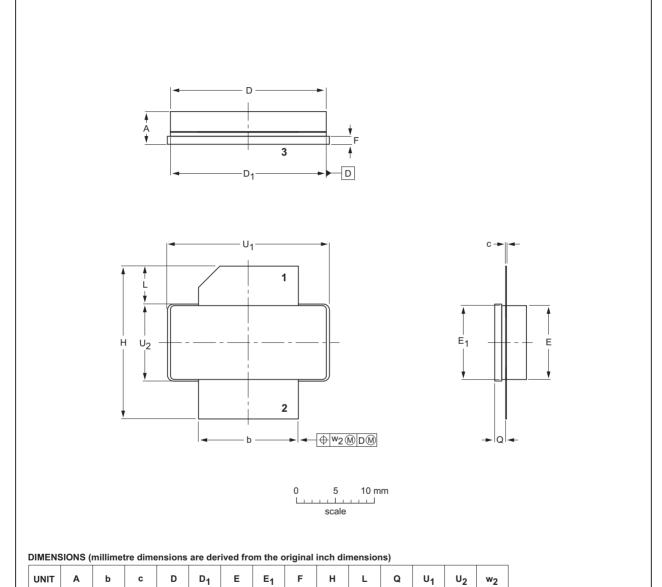


OUTLINE		REFER	ENCES	EUROPEAN	ISSUE DATE
VERSION	IEC	JEDEC	JEITA	PROJECTION	ISSUE DATE
SOT502A					-03-01-10 - 12-05-02

Fig 11. Package outline SOT502A

Earless flanged ceramic package; 2 leads

SOT502B



mm	4.72 3.43	12.83 12.57	0.15 0.08	20.02 19.61	19.96 19.66	9.50 9.30	9.53 9.25	1.14 0.89	19.94 18.92	5.33 4.32	1.70 1.45	20.70 20.45	9.91 9.65	0.25
inches	0.186 0.135	0.505 0.495							0.785 0.745			0.815 0.805		0.010

OUTLINE		REFER	ENCES	EUROPEAN	ISSUE DATE
VERSION	IEC	JEDEC	JEITA	PROJECTION	ISSUE DATE
SOT502B					07-05-09 12-05-02

Fig 12. Package outline SOT502B

9. Abbreviations

Table 9. Abbreviations

Acronym	Description
3GPP	Third Generation Partnership Project
CCDF	Complementary Cumulative Distribution Function
CW	Continuous Wave
DPCH	Dedicated Physical CHannel
ESD	ElectroStatic Discharge
LDMOS	Laterally Diffused Metal Oxide Semiconductor
LDMOST	Laterally Diffused Metal Oxide Semiconductor Transistor
PAR	Peak-to-Average power Ratio
PDPCH	transmission Power of the Dedicated Physical CHannel
RF	Radio Frequency
VSWR	Voltage Standing Wave Ratio
W-CDMA	Wideband Code Division Multiple Access

10. Revision history

Table 10. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
BLF7G20L-200_7G20LS-200#5	20150901	Product data sheet	-	BLF7G20L-200_7G20LS-200 v.4
Modifications:	 The format of this document has been redesigned to comply with the new identity guidelines of Ampleon. 			
	 Legal tex 	ts have been adapted to	the new compa	ny name where appropriate.
BLF7G20L-200_7G20LS-200 v.4	20110722	Product data sheet	-	BLF7G20L-200_7G20LS-200 v.3
BLF7G20L-200_7G20LS-200 v.3	20110301	Preliminary data sheet	-	BLF7G20L-200_7G20LS-200 v.2
BLF7G20L-200_7G20LS-200 v.2	20100827	Preliminary data sheet	-	BLF7G20L-200_7G20LS-200 v.1
BLF7G20L-200_7G20LS-200 v.1	20100603	Objective data sheet	-	-

11. Legal information

11.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
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BLF7G20L-200; BLF7G20LS-200

Power LDMOS transistor

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AMPLEON

Power LDMOS transistor

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